Vishay Semiconductors

AUTOMOTIVE

COMPLIANT

GREEN (5-2008)

Low Current Mini SMD LED



DESCRIPTION

The new low current MiniLED Series have been designed in a small white SMT package. The feature of the device is the very small package 2.3 mm x 1.3 mm x 1.4 mm and the low forward current. The MiniLED is an obvious solution for small-scale, high-power products that are expected to work reliability in an arduous environment. This is often the case in automotive and industrial application.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED
Package: SMD MiniLED
Product series: low current
Angle of half intensity: ± 60°

FEATURES

- SMD LED with exceptional brightness
- · Luminous intensity categorized
- Compatible with automatic placement equipment
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- IR reflow soldering according to J-STD-020
- \bullet Luminous intensity ratio in one packaging unit $I_{Vmax.}/I_{Vmin.} \leq 2.0$
- · Preconditioning: according to JEDEC level 2a
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- · Indicator and backlight for audio and video equipment
- · Indicator and backlight in office equipment
- Flat backlight for LCDs, switches, and symbols

PARTS TABLE	PARTS TABLE											
PART	COLOR			at I _F (nm)			FORWARD VOLTAGE (V)			TECHNOLOGY		
		MIN.	TYP.	MAX.	(mA)	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
VLMS2000-GS08	Super red	2.24	4.5	-	2	-	630	-	-	1.8	2.2	AllnGaP on GaAs
VLMS20H2K1-GS08	Super red	3.55	-	9	2	-	630	-	-	1.8	2.2	AllnGaP on GaAs
VLMS20H2L1-GS08	Super red	3.55	-	14	2	-	630	-	-	1.8	2.2	AllnGaP on GaAs
VLMS20J2K2-GS08	Super red	5.6	-	11.2	2	-	630	-	-	1.8	2.2	AllnGaP on GaAs
VLMS20J2L1-GS08	Super red	5.6	-	14	2	-	630	-	-	1.8	2.2	AllnGaP on GaAs
VLMO2000-GS08	Soft orange	4.5	9	-	2	598	605	611	-	1.8	2.2	AllnGaP on GaAs
VLMO20J2M1-GS08	Soft orange	5.6	-	22.4	2	598	605	611	-	1.8	2.2	AllnGaP on GaAs
VLMO20K1L2-34-GS08	Soft orange	7.1	-	18	2	602	-	607	-	1.8	2.2	AllnGaP on GaAs
VLMO20K2L2-35-GS08	Soft orange	9	-	18	2	602	-	609	-	1.8	2.2	AllnGaP on GaAs
VLMY2000-GS08	Yellow	3.55	7.1	-	2	581	588	594	-	1.8	2.2	AllnGaP on GaAs
VLMY20J1L2-GS08	Yellow	4.5	-	18	2	581	588	594	-	1.8	2.2	AllnGaP on GaAs
VLMY20K1L2-GS08	Yellow	7.1	-	18	2	581	588	594	-	1.8	2.2	AllnGaP on GaAs
VLMK20J2L1-GS08	Amber	5.6	-	14	2	612	622	624	-	1.8	2.2	AllnGaP on GaAs
VLMK20J2L2-GS08	Amber	5.6	-	18	2	612	622	624	-	1.8	2.2	AllnGaP on GaAs
VLMK2000-GS08	Amber	7.1	16	-	2	612	622	624	-	1.8	2.2	AllnGaP on GaAs
VLMK20K1L2-GS08	Amber	7.1	-	18	2	612	622	624	-	1.8	2.2	AllnGaP on GaAs
VLMP20D2G1-GS08	Pure green	0.56	-	2.24	2	555	-	565	-	1.8	2.2	AllnGaP on GaAs

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	ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) VLMO20, VLMS20, VLMY20, VLMP20						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Reverse voltage (1)		V_R	5	V			
DC forward current	T _{amb} ≤ 100 °C	I _F	15	mA			
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.1	Α			
Power dissipation		Pv	40	mW			
Junction temperature		T_j	+ 125	°C			
Operating temperature range		T _{amb}	- 40 to + 100	°C			
Storage temperature range		T _{stg}	- 40 to + 100	°C			
Thermal resistance junction/ambient	Mounted on PC board (pad size > 5 mm ²)	R_{thJA}	580	K/W			

Note

⁽¹⁾ Driving the LED in reverse direction is suitable for a short term application

VLMS20, SUPER RED PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT							
PANAMETEN	TEST CONDITION		STIVIDUL			IVIAA.	
		VLMS2000-GS08	I _V	2.24	4.5	-	mcd
		VLMS20H2K1-GS08	I _V	3.55	-	9	mcd
Luminous intensity (1)	$I_F = 2 \text{ mA}$	VLMS20H2L1-GS08	Ι _V	3.55	-	14	mcd
		VLMS20J2K2-GS08	l _V	5.6	-	11.2	mcd
		VLMS20J2L1-GS08	Ι _V	5.6	-	14	mcd
Dominant wavelength	I _F = 2 mA		λ_{d}	-	630	-	nm
Peak wavelength	I _F = 2 mA		λ_{p}	-	643	-	nm
Angle of half intensity	I _F = 2 mA		φ	-	± 60	-	deg
Forward voltage	I _F = 2 mA		V_{F}	-	1.8	2.2	V
Reverse voltage	I _R = 10 μA		V_{R}	5	-	-	V
Junction capacitance	V _R = 0 V, f = 1 MHz		C _i	-	15	-	pF

Note

 $^{^{(1)}}$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 2.0$

VLMO20, SOFT O	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		VLMO2000-GS08	l _V	4.5	9	-	mcd
1 (1)	1 0	VLMO20J2M1-GS08	l _V	5.6	-	22.4	mcd
Luminous intensity (1)	$I_F = 2 \text{ mA}$	VLMO20K1L2-34-GS08	l _V	7.1	-	18	mcd
		VLMO20K2L2-35-GS08	l _V	9	-	18	mcd
		VLMO20K2L2-35	λ_{d}	602	-	609	nm
Dominant wavelength	$I_F = 2 \text{ mA}$	VLMO20K1L2-34	λ_{d}	602	-	607	nm
		VLMO20	λ_{d}	598	605	611	nm
Peak wavelength	I _F = 2 mA		λ_{p}	-	610	=	nm
Angle of half intensity	I _F = 2 mA		φ	-	± 60	=	deg
Forward voltage	I _F = 2 mA		V_{F}	-	1.8	2.2	V
Reverse voltage	I _R = 10 μA		V_R	5	-	=	V
Junction capacitance	V _R = 0 V, f = 1 MHz		C _i	-	15	-	pF

Note

 $^{^{(1)}}$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 2.0$



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OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 ^{\circ}\text{C}$, unless otherwise specified) VLMY20, YELLOW							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity (1)	I _E = 2 mA	VLMY2000-GS08	l _V	3.55	7.1	-	mcd
Luminous intensity (1)	IF = 2 IIIA	VLMY20J1L2-GS08	Ι _V	4.5	-	18	mcd
		VLMY20K1L2-GS08	l _V	7.1	-	18	mcd
Dominant wavelength	I _F = 2 mA		λ_{d}	581	588	594	nm
Peak wavelength	$I_F = 2 \text{ mA}$		λ_{p}	-	590	-	nm
Angle of half intensity	$I_F = 2 \text{ mA}$		φ	=	± 60	-	deg
Forward voltage	I _F = 2 mA		V _F	-	1.8	2.2	V
Reverse voltage	I _R = 10 μA		V_R	5	-	-	V
Junction capacitance	V _R = 0 V, f = 1 MHz		Cj	-	15	-	pF

Note

⁽¹⁾ In one packing unit $I_{Vmax.}/I_{Vmin.} \le 2.0$

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified) VLMK20, AMBER							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		VLMK20J2L1-GS08	l _V	5.6	-	14	mcd
Luminous intensity (1)	$I_F = 2 \text{ mA}$	VLMK20J2L2-GS08	l _V	5.6	-	18	mcd
		VLMK2000-GS08	l _V	7.1	16	-	mcd
		VLMK20K1L2-GS08	l _V	7.1	-	18	mcd
Dominant wavelength	$I_F = 2 \text{ mA}$		λ_{d}	612	622	624	nm
Peak wavelength	$I_F = 2 \text{ mA}$		λ_{p}	-	615	-	nm
Angle of half intensity	$I_F = 2 \text{ mA}$		φ	-	± 60	=.	deg
Forward voltage	$I_F = 2 \text{ mA}$		V_{F}	-	1.8	2.2	V
Reverse voltage	I _R = 10 μA		V_{R}	5	-	-	V
Junction capacitance	V _R = 0 V, f = 1 MHz		C _i	-	15	-	pF

Note

 $^{^{(1)}}$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 2.0$

OPTICAL AND ELECTRICAL CHARACTERISTICS ($T_{amb} = 25 ^{\circ}C$, unless otherwise specified) VLMP20, PURE GREEN							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity (1)	I _F = 2 mA	VLMP20D2G1	Ι _V	0.56	-	2.24	mcd
Dominant wavelength	I _F = 2 mA		λ _d	555	-	565	nm
Peak wavelength	I _F = 2 mA		λρ	=	565	-	nm
Angle of half intensity	I _F = 2 mA		φ	=	± 60	-	deg
Forward voltage	I _F = 2 mA		V _F	=	1.8	2.2	V
Reverse voltage	I _R = 10 μA		V _R	5	-	-	V
Junction capacitance	V _R = 0 V, f = 1 MHz		C _i	-	15	-	pF

Note

 $^{^{(1)}~}$ In one packing unit $I_{Vmax.}/I_{Vmin.} \leq 2.0$

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COLOR CLASSIFICATION										
		DOM. WAVELENGTH (nm)								
GROUP	SOFT C	RANGE	YEL	LOW	AM	BER	PURE	GREEN		
=	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
0	-	-	-	-	-	=	555	559		
1	598	601	581	584	-	-	558	561		
2	600	603	583	586	-	-	560	563		
3	602	605	585	588	-	=	562	565		
4	604	607	587	590	-	-	-	-		
5	606	609	589	592	-	-	-	-		
6	608	611	591	594	-	=	-	-		
7	-	-	-	-	610	613	-	-		
8	-	-	-	-	612	616	-	-		
9	-	-	-	-	615	620	-	-		
10	-	-	_	-	619	624	-	-		

Note

• Wavelengths are tested at a current pulse duration of 25 ms.

LUMINOUS INTENSITY CLASSIFICATION								
GROUP	LUMIN	LUMINOUS INTENSITY I _V (mcd)						
STANDARD	OPTIONAL	MIN.	MAX.					
D	2	0.56	0.71					
E	1	0.71	0.9					
E	2	0.9	1.12					
F	1	1.12	1.4					
Г	2	1.4	1.8					
G	1	1.8	2.24					
G	2	2.24	2.8					
Н	1	2.8	3.55					
П	2	3.55	4.5					
J	1	4.5	5.6					
J	2	5.6	7.1					
K	1	7.1	9					
r.	2	9	11.2					
L	1	11.2	14					
L	2	14	18					
М	1	18	22.4					
IVI	2	22.4	35.5					
N	1	35.5	45					
IN	2	45	56					

CROSSING TABLE	
VISHAY	OSRAM
VLMS20H2K1	LSM67K-H2K1
VLMS20J2L1	LSM67K-J2L1
VLMS20H2L1	LSM67K-H2L1
VLMO20J2L1	LOM67K-J2L1
VLMO20J2M1	LOM67K-J2M1
VLMY20J1K2	LYM67K-J1K2
VLMY20K1L2	LYM67K-K1L2
VLMY20J1L2	LYM67K-J1L2
VLMP20D2G1	LPM67K-D2G1
VLMP20E2G1	LPM67K-E2G1

Note

 Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped in any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

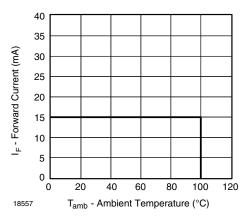


Fig. 1 - Forward Current vs. Ambient Temperature

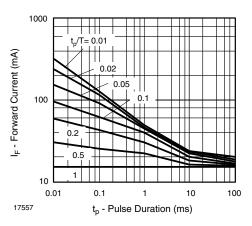


Fig. 2 - Forward Current vs. Pulse Length

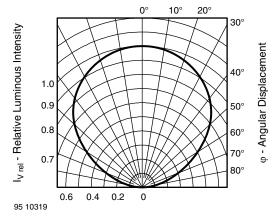


Fig. 3 - Relative Luminous Intensity vs. Angular Displacement

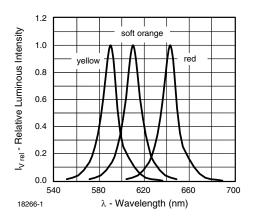


Fig. 4 - Relative Intensity vs. Wavelength

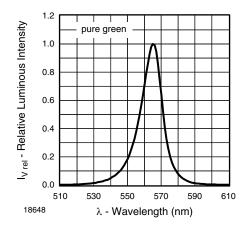


Fig. 5 - Relative Luminous Intensity vs. Wavelength

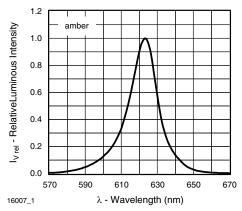


Fig. 6 - Relative Luminous Intensity vs. Wavelength

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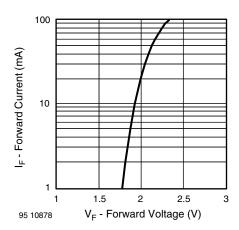


Fig. 7 - Forward Current vs. Forward Voltage

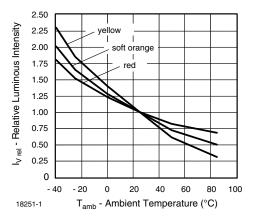


Fig. 8 - Relative Luminous Intensity vs. Ambient Temperature

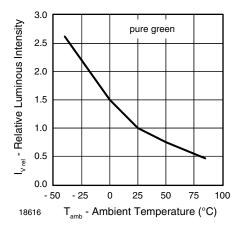


Fig. 9 - Relative Luminous Intensity vs. Ambient Temperature

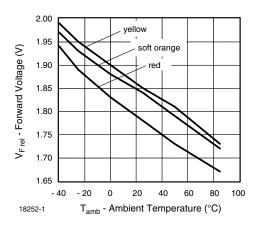


Fig. 10 - Forward Voltage vs. Ambient Temperature

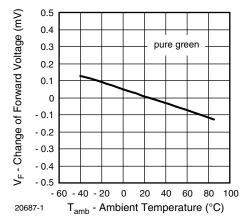
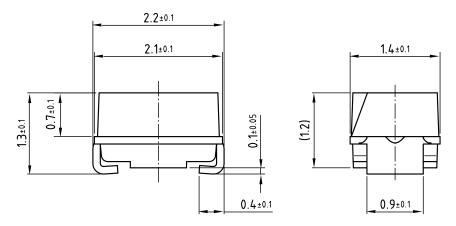


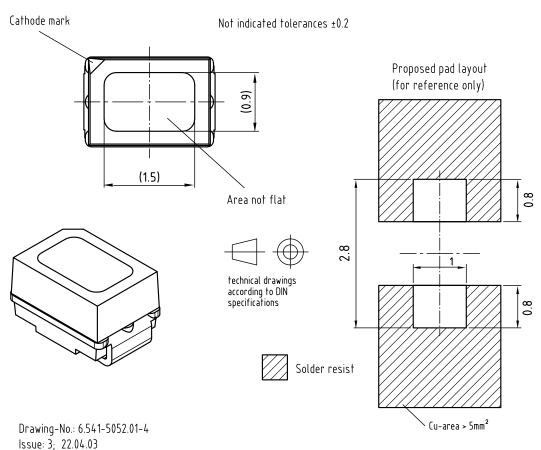
Fig. 11 - Change of Forward Voltage vs. Ambient Temperature

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PACKAGE DIMENSIONS in millimeters

16892



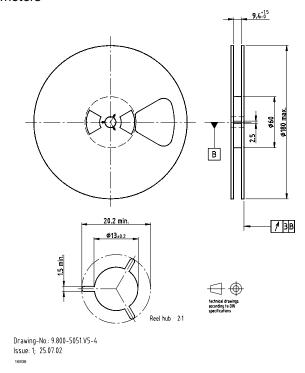


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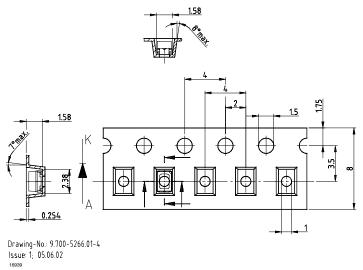
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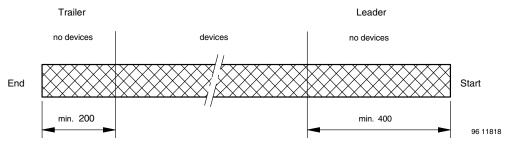
REEL DIMENSIONS in millimeters



TAPE DIMENSIONS in millimeters



LEADER AND TRAILER DIMENSIONS in millimeters



GS08 = 3000 pcs

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COVER TAPE PEEL STRENGTH

According to DIN EN 60286-3 0.1 N to 1.3 N 300 ± 10 mm/min 165° to 180° peel angle

LABEL

Standard bar code labels for finished goods

The standard bar code labels are product labels and used for identification of goods. The finished goods are packed in final packing area. The standard packing units are labeled with standard bar code labels before transported as finished goods to warehouses. The labels are on each packing unit and contain Vishay Semiconductor GmbH specific data.

D. A.D. 14/D. III. 14		
PLAIN WRITING	ABBREVIATION	LENGTH
Item-description	-	18
Item-number	INO	8
Selection-code	SEL	3
LOT-/serial-number	BATCH	10
Data-code	COD	3 (YWW)
Plant-code	PTC	2
Quantity	QTY	8
Accepted by:	ACC	-
Packed by:	PCK	-
Mixed code indicator	MIXED CODE	-
Origin	xxxxxx+	Company Logo
LONG BAR CODE TOP	TYPE	LENGTH
Item-number	N	8
Plant-code	N	2
Sequence-number	X	3
Quantity	N	8
Total length	-	21
SHORT BAR CODE BOTTOM	TYPE	LENGTH
Selection-code	X	3
Data-code	N	3
Batch-number	X	10
Filter	-	1
Total length	-	17

SOLDERING PROFILE

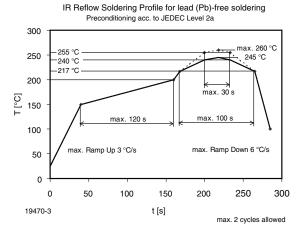
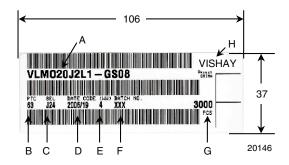


Fig. 12 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

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BAR CODE PRODUCT LABEL (example)

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- A. Type of component
- B. Manufacturing plant
- C. SEL selection code (bin):

e.g.: J2 = code for luminous intensity group

4 = code for color group

D. Date code year/week

E. Day code (e.g. 4: Thursday)

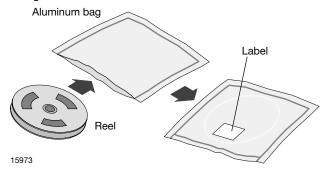
F. Batch no.

G. Total quantity

H. Company code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOF OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

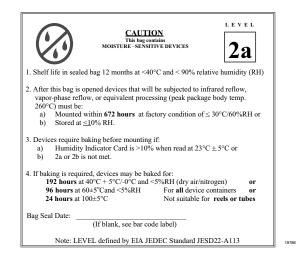
After more than 672 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition: 192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 $^{\circ}\text{C}$ + 5 $^{\circ}\text{C}$ and < 5 $^{\circ}$ RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



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Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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